

RD4.7SL to RD39SL

ZENER DIODES
200 mW 2 PIN SUPER MINI MOLD

DESCRIPTION

Type RD4.7SL to RD39SL Series are 2 PIN Super Mini Mold Package zener diodes possessing an allowable power dissipation of 200 mW featuring low noise and sharp breakdown characteristic. They are intended for use in audio equipment, instrument equipment.

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the device and its recommended applications

FEATURES

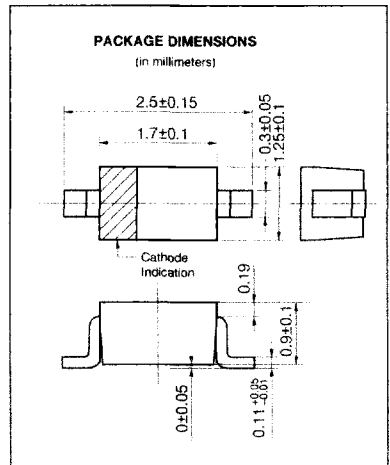
- Low Noise
- Sharp Breakdown characteristic.
- Vz: Applied E24 standard.

APPLICATIONS

Circuits for Constant Voltage, Constant Current, Waveform Clipper, Surge absorber, etc.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ }^\circ\text{C}$)

Power Dissipation	P	200 mW
Forward Current	I_F	100 mA
Reverse Surge Power	P_{RSM}	2.3W (at $t=10\text{ }\mu\text{s}/1\text{ pulse}$) Show fig. 8
Junction Temperature	T_j	150 $^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150 $^\circ\text{C}$



ELECTRICAL CHARACTERISTICS (T_A = 25 ± 2 °C)

Type Number	Class	Zener Voltage V _Z (V)*			Dynamic Impedance Z _Z (Ω)**		Reverse Current I _R (μA)	
		MIN.	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	V _R (V)
RD4.7SL	N	4.39	4.91	0.5	800	0.5	2	1.0
	N1	4.39	4.62					
	N2	4.52	4.76					
	N3	4.66	4.91					
RD5.1SL	N	4.81	5.36	0.5	500	0.5	2	1.5
	N1	4.81	5.05					
	N2	4.95	5.20					
	N3	5.10	5.36					
RD5.6SL	N	5.26	5.91	0.5	200	0.5	1	2.5
	N1	5.26	5.54					
	N2	5.44	5.73					
	N3	5.63	5.91					
RD6.2SL	N	5.81	6.53	0.5	100	0.5	1	3.0
	N1	5.81	6.11					
	N2	6.01	6.32					
	N3	6.21	6.53					
RD6.8SL	N	6.41	7.14	0.5	60	0.5	0.5	3.5
	N1	6.41	6.74					
	N2	6.60	6.94					
	N3	6.80	7.14					
RD7.5SL	N	7.00	7.83	0.5	60	0.5	0.5	4.0
	N1	7.00	7.35					
	N2	7.21	7.60					
	N3	7.46	7.83					
RD8.2SL	N	7.69	8.61	0.5	60	0.5	0.5	5.0
	N1	7.69	8.08					
	N2	7.94	8.34					
	N3	8.20	8.61					
RD9.2SL	N	8.47	9.51	0.5	60	0.5	0.5	6.0
	N1	8.47	8.91					
	N2	8.76	9.21					
	N3	9.06	9.51					
RD10SL	N	9.35	10.51	0.5	60	0.5	0.1	7.0
	N1	9.35	9.82					
	N2	9.66	10.16					
	N3	10.00	10.51					
RD11SL	N	10.32	11.50	0.5	60	0.5	0.1	8.0
	N1	10.32	10.84					
	N2	10.64	11.17					
	N3	10.97	11.50					

ELECTRICAL CHARACTERISTICS (T_A = 25 ± 2 °C)

Type Number	Class	Zener Voltage V _Z (V)*			Dynamic Impedance Z _Z (Ω)**		Reverse Current I _R (μA)	
		MIN.	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	V _R (V)
RD12SL	N	11.28	12.52	0.5	80	0.5	0.1	9.0
	N1	11.28	11.83					
	N2	11.59	12.17					
	N3	11.93	12.52					
RD13SL	N	12.29	13.86	0.5	80	0.5	0.1	10
RD15SL	N	13.63	15.38	0.5	80	0.5	0.1	11
RD16SL	N	15.13	16.91	0.5	80	0.5	0.1	12
RD18SL	N	16.63	18.81	0.5	80	0.5	0.1	13
RD20SL	N	18.51	20.79	0.5	100	0.5	0.1	15
RD22SL	N	20.46	22.82	0.5	100	0.5	0.1	17
RD24SL	N	22.42	25.17	0.5	120	0.5	0.1	19
RD27SL	N	24.75	27.95	0.5	150	0.5	0.1	21
RD30SL	N	27.38	31.04	0.5	200	0.5	0.1	23
RD33SL	N	30.30	33.97	0.5	250	0.5	0.1	25
RD36SL	N	33.08	36.83	0.5	300	0.5	0.1	27
RD39SL	N	35.78	39.67	0.5	360	0.5	0.1	30

* V_Z is tested with puls (40 mS).

** Z_Z is measured at I_Z by given a very small A.C. current signal.

TYPICAL CHATACTERISTICS (T_A = 25 °C)

Fig. 1 POWER DISSIPATION vs. AMBIENT TEMPERATURE

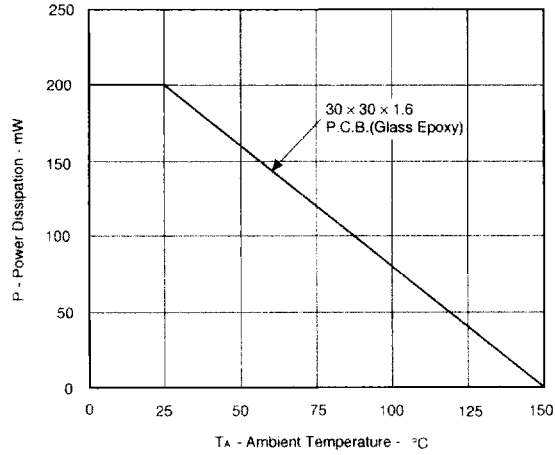


Fig.2 ZENER CURRENT vs. ZENER VOLTAGE

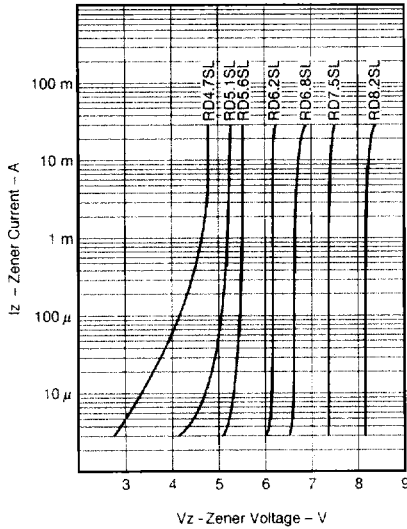


Fig. 3 ZENER CURRENT vs. ZENER VOLTAGE

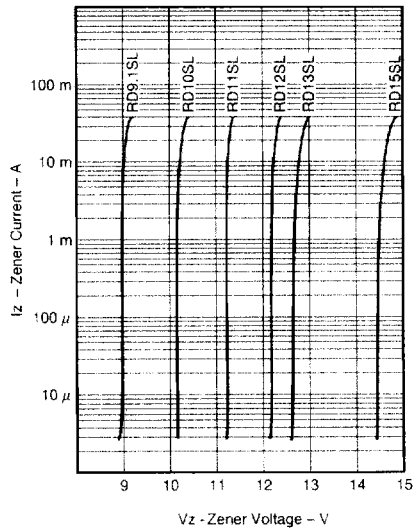


Fig. 4 ZENER CURRENT vs. ZENER VOLTAGE

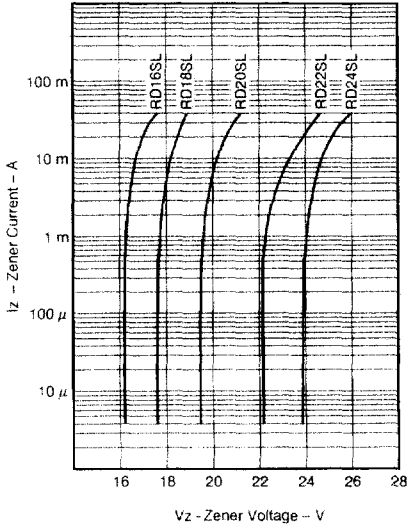


Fig. 5 ZENER CURRENT vs. ZENER VOLTAGE

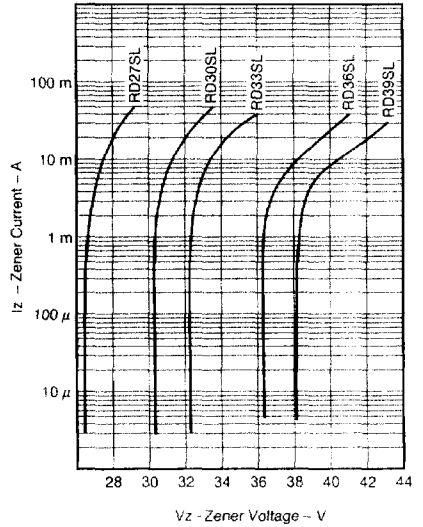


Fig. 6 ZENER VOLTAGE TEMPERATURE COEFFICIENT vs. ZENER VOLTAGE

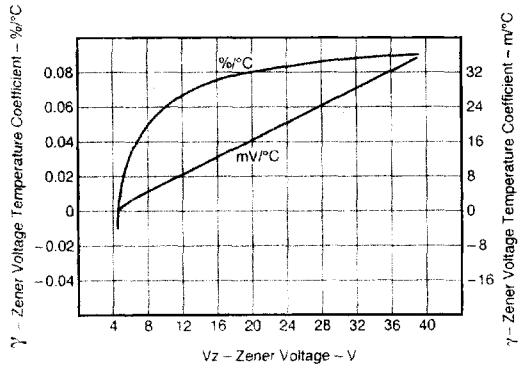


Fig.7 TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC

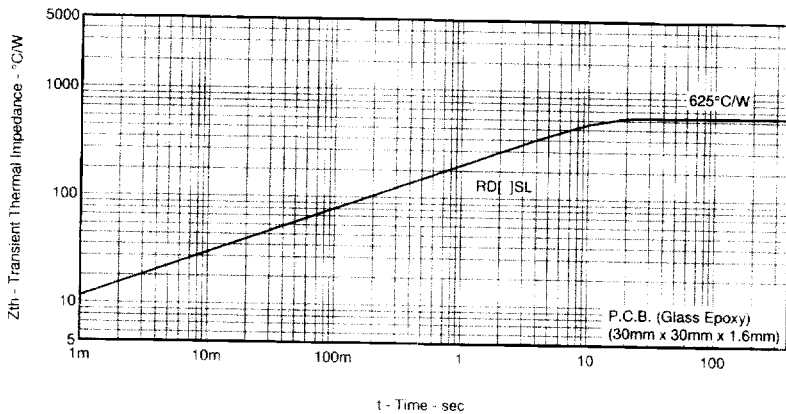


Fig.8 SURGE REVERSE POWER RATINGS

